

## Supplementary material

### Ammonium Formate-Engineered MA-free Perovskite Ink for Solar Cells and Optoelectronic Devices

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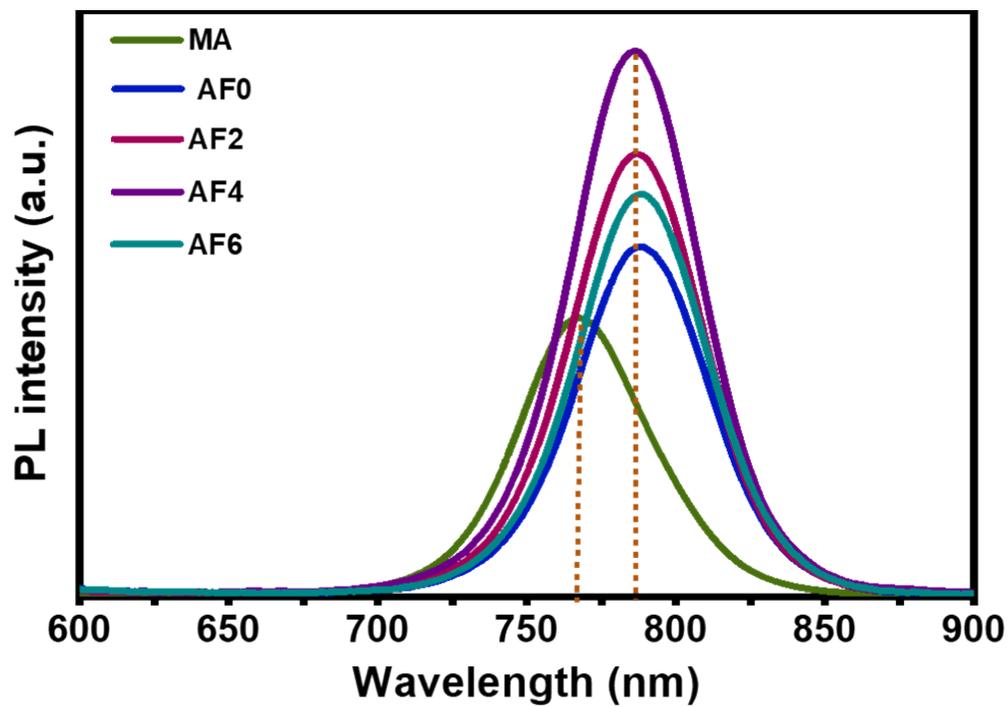


Fig. S1. PL spectrum for perovskite films with and without MA in presence of  $\text{NH}_4\text{Fo}$  at different concentration.

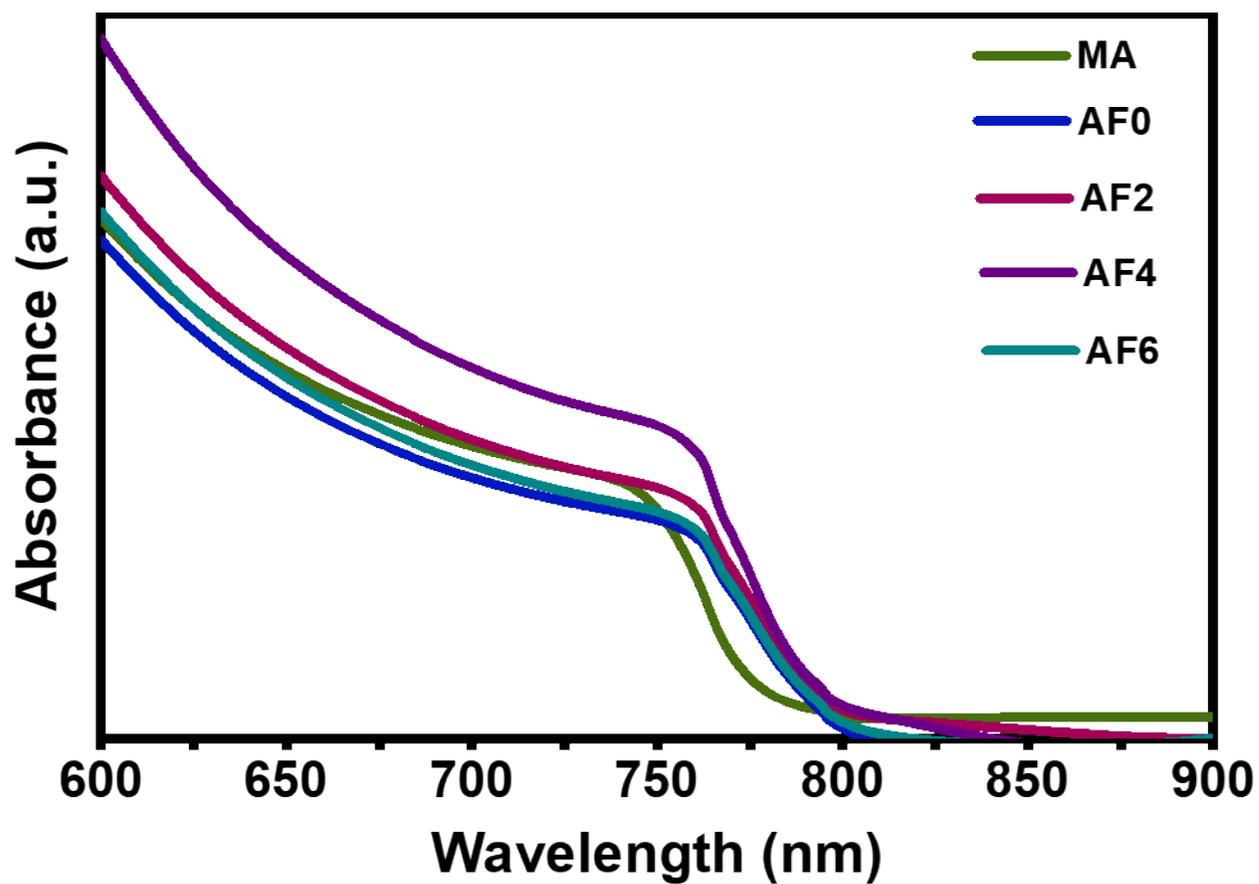


Fig. S2. UV-Vis absorption for perovskite films with and without MA in presence of  $\text{NH}_4\text{Fo}$  at different concentration.

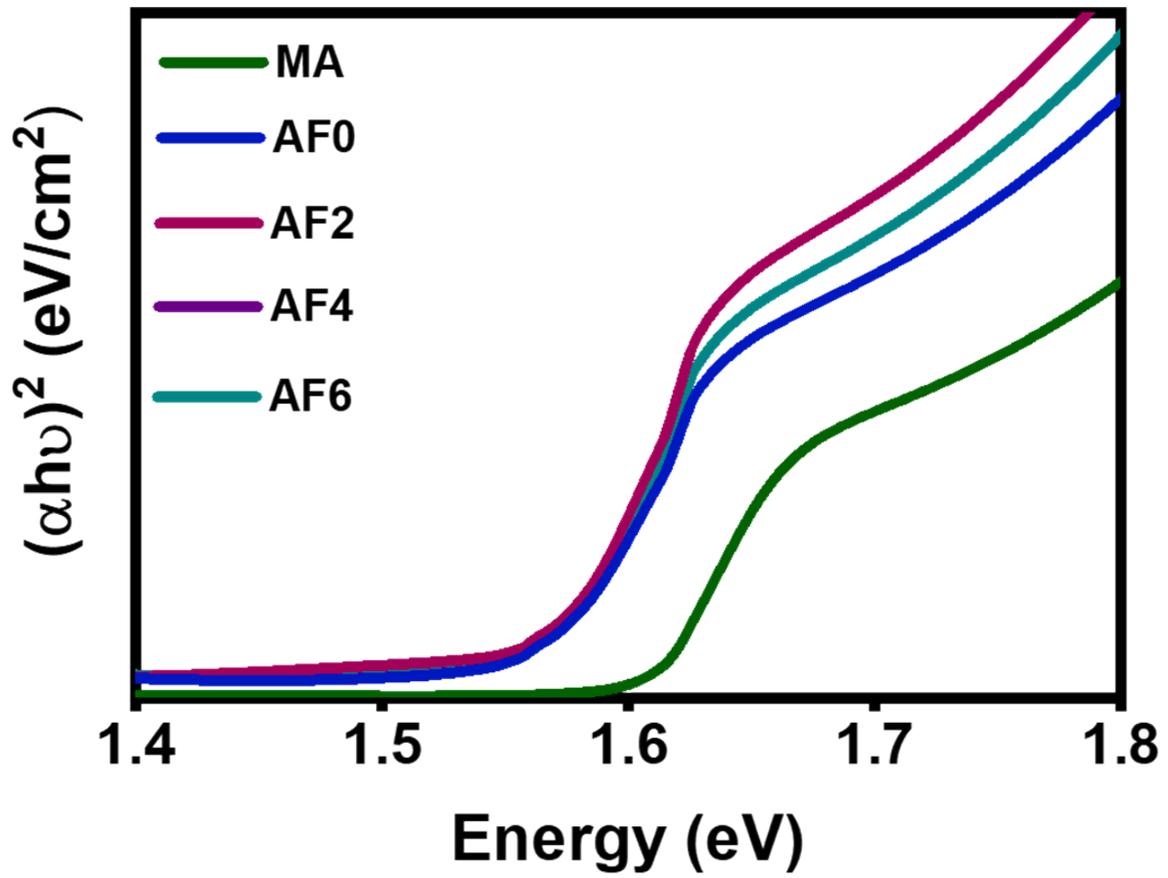


Fig. S3. Tauc plot for perovskite films with and without MA in presence of  $\text{NH}_4\text{Fo}$  at different concentration.

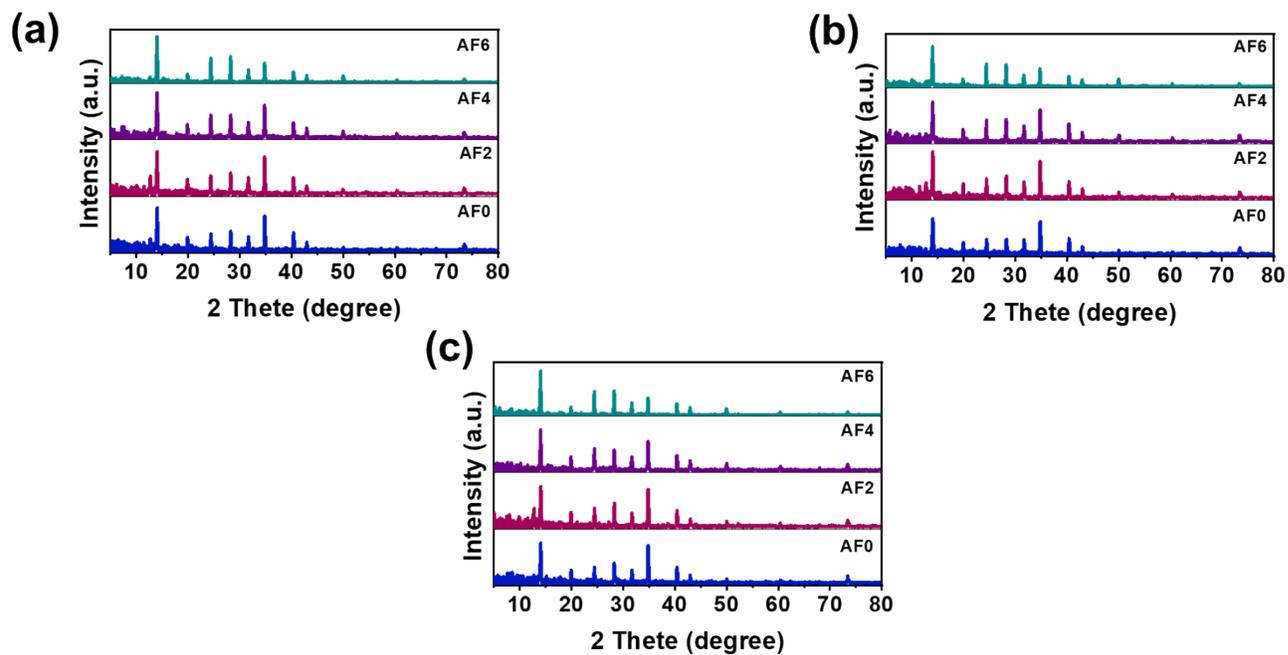


Fig. S4. XRD spectra of perovskite layers with and without  $\text{NH}_4\text{Fo}$  in different concentration at different days, (a) first day, (b) after 7 days and (c) after 14 days.

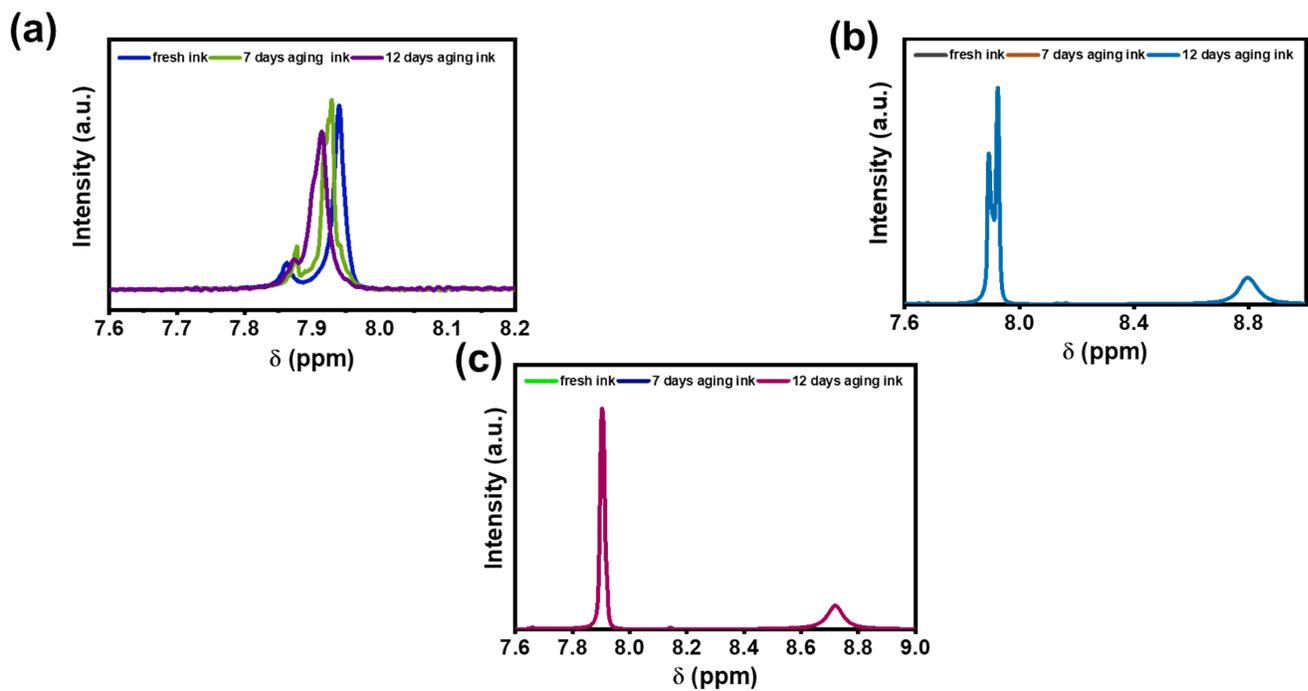


Fig. S5.  $^1\text{H}$  NMR spectra of perovskite layers with (a) MA, (b) without MA, and (c) without MA in presence of  $\text{NH}_4\text{Fo}$  4% mol.

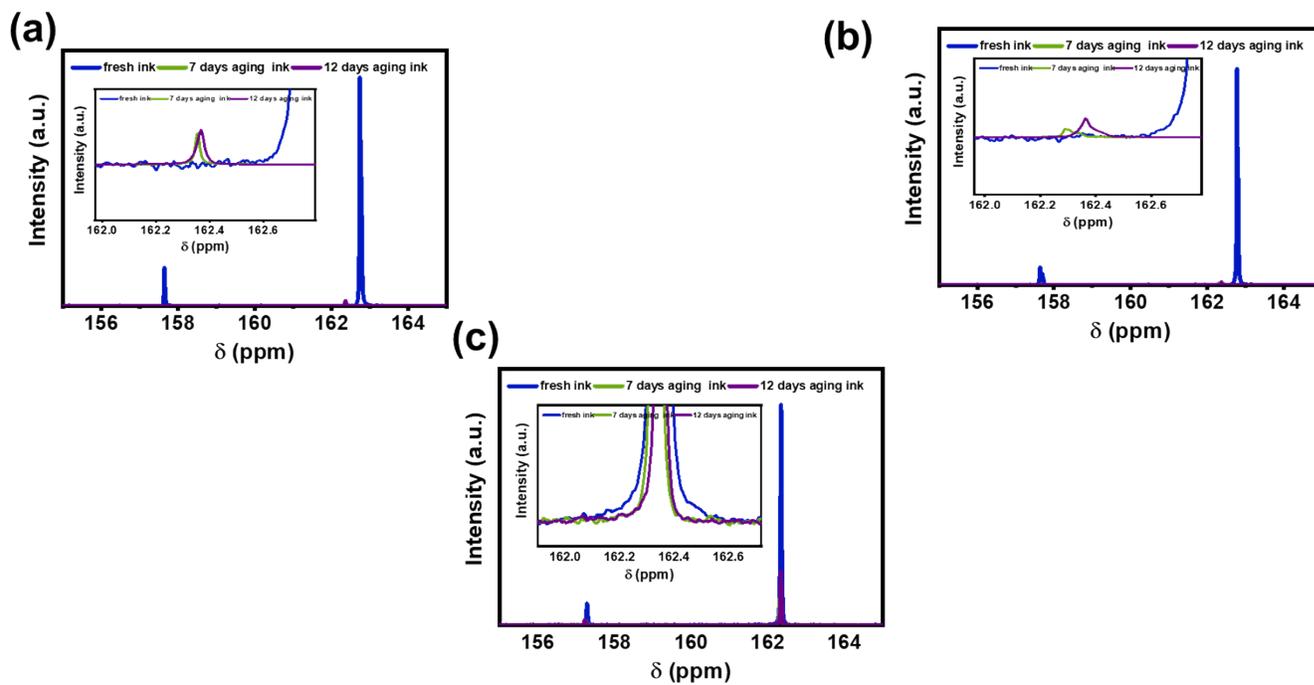


Fig. S6.  $^{13}\text{C}$  NMR spectra of perovskite layers with (a) MA, (b) without MA, and (c) without MA in presence of  $\text{NH}_4\text{Fo}$  4% mol.

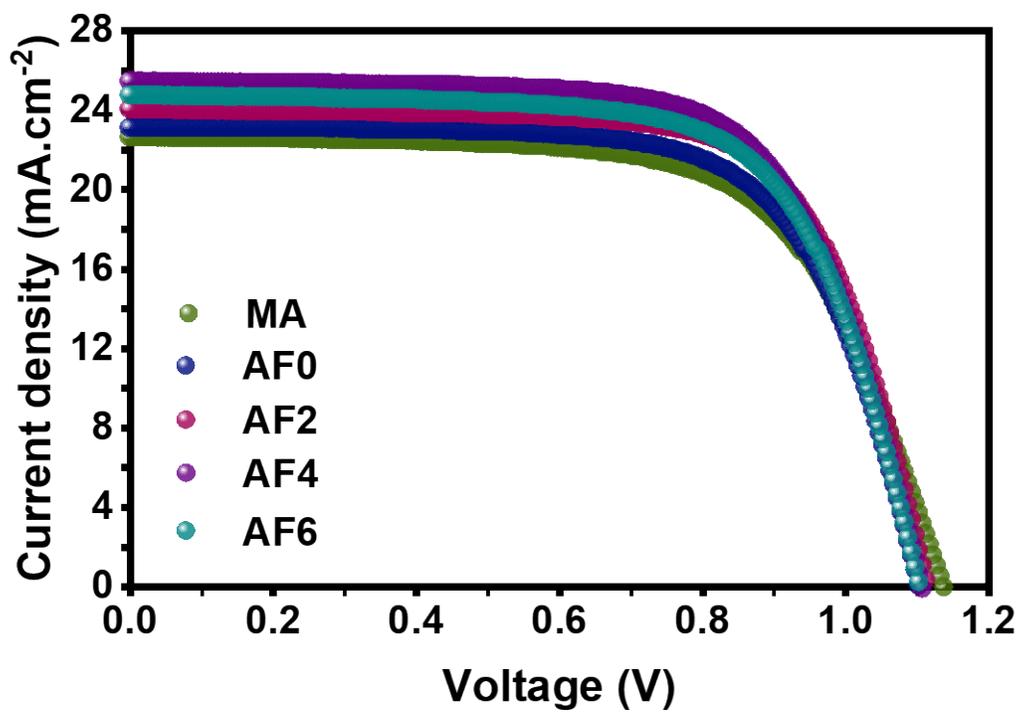


Fig. S7. J–V curves of the best performing PSCs based on MA and MA-free in presence of NH<sub>4</sub>Fo at different concentration.

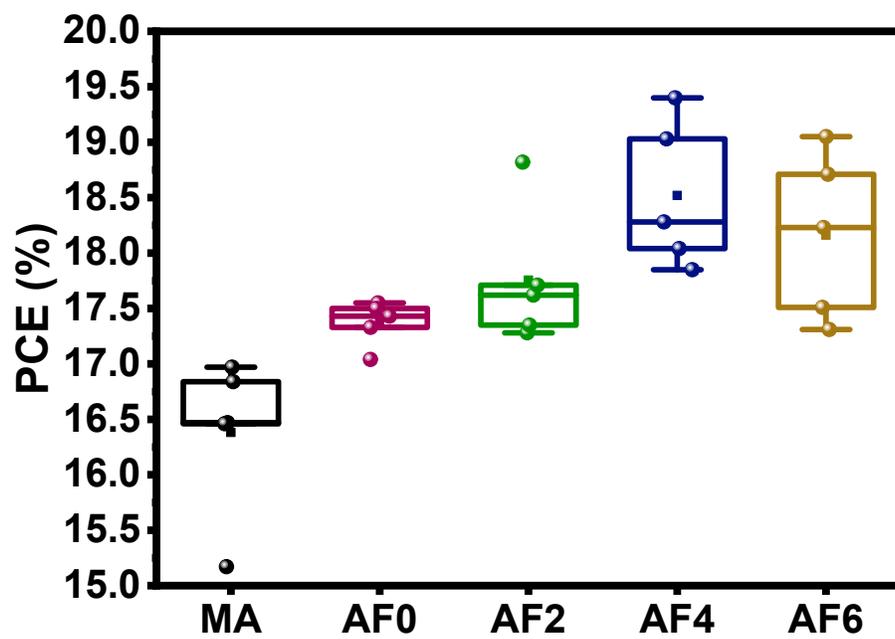


Fig. S8. Performance statistics of PSCs based on MA, MA-free and MA-free in presence of  $\text{NH}_4\text{Fo}$  at different concentration.

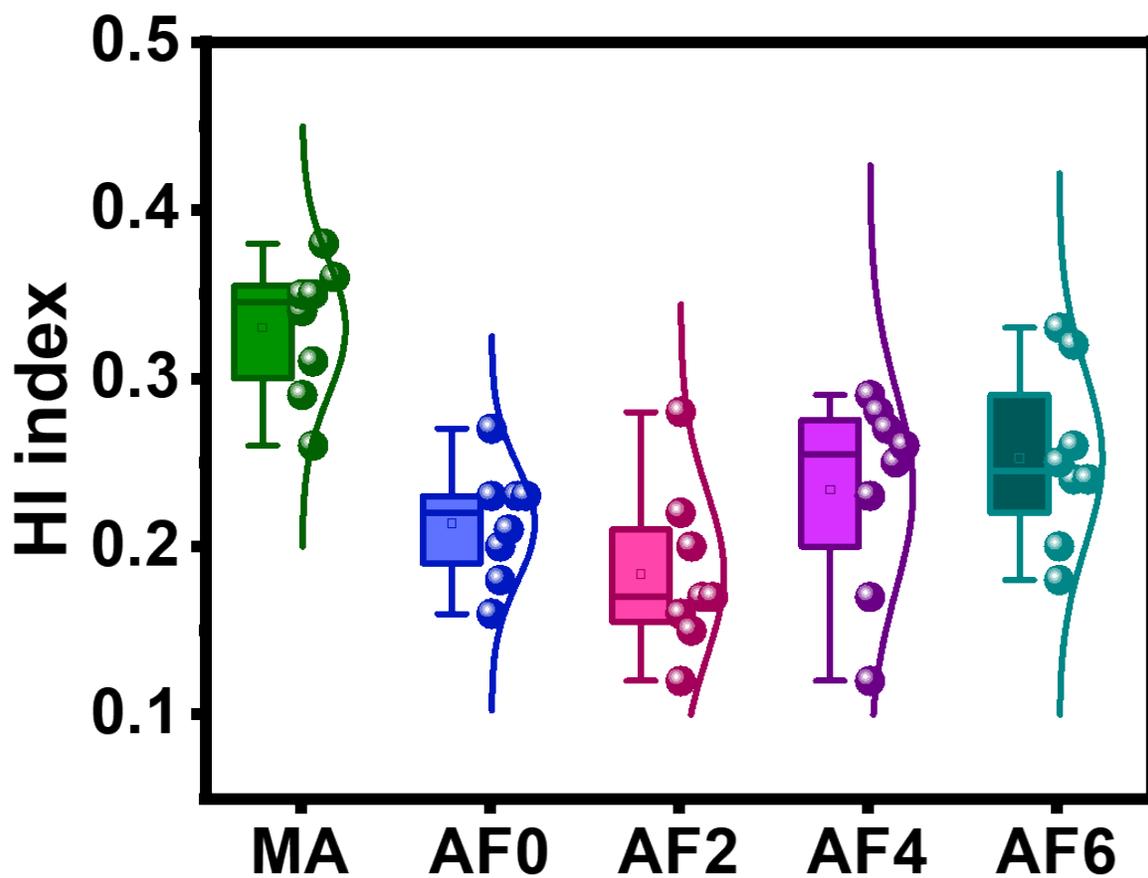


Fig. S9. HI index distribution of the PSCs based on MA and MA-free in presence of  $\text{NH}_4\text{Fo}$  at different concentration.

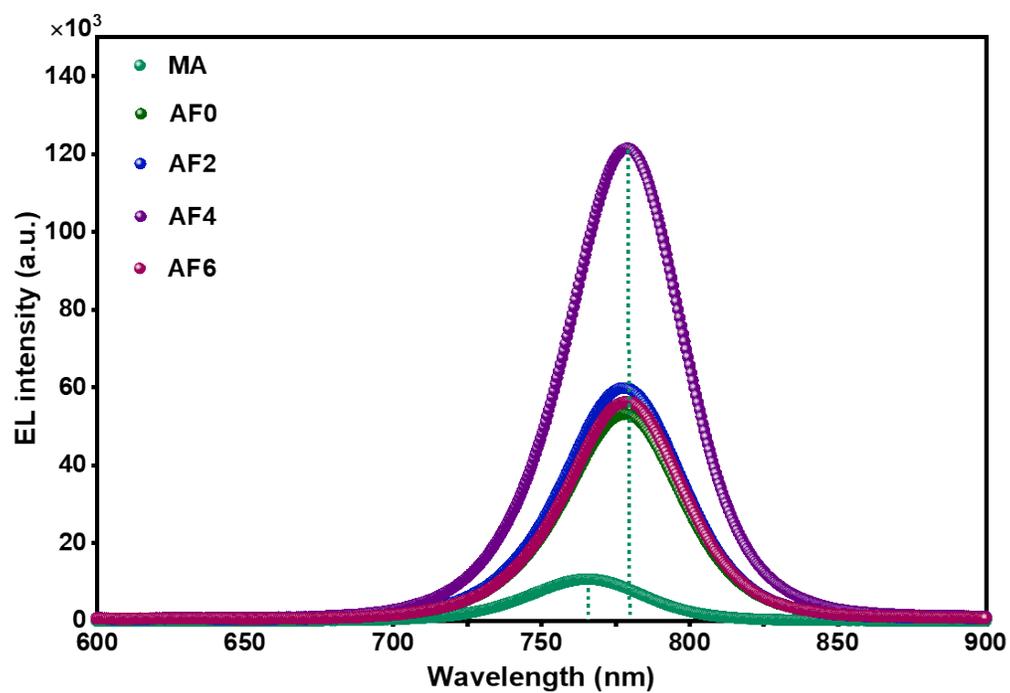


Fig. S10. EL spectra of the best performing PSCs based on MA and MA-free in presence of  $\text{NH}_4\text{Fo}$  at different concentration.

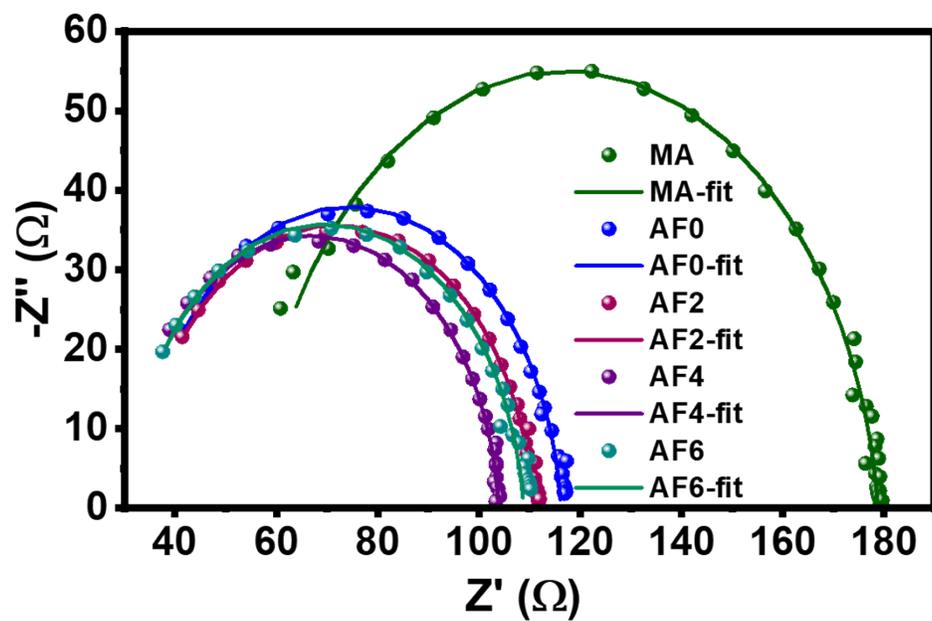


Fig. S11. Nyquist plots of the best performing PSCs based on MA and MA-free in presence of  $\text{NH}_4\text{Fo}$  at different concentration.

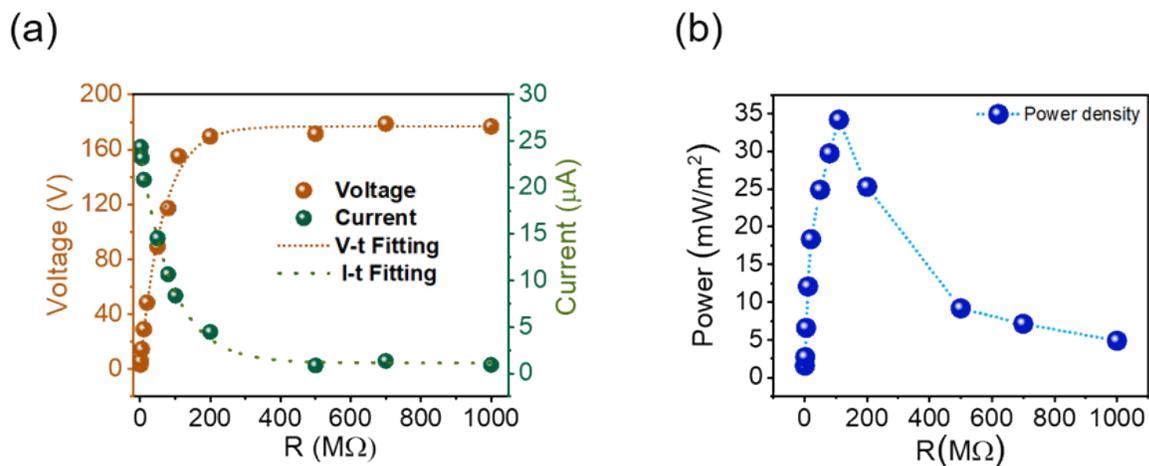


Fig. S12. (a) The current and voltage amplitude vs different load resistance and (b) The generated power density vs. load resistance for FTO/Kapton CS-TENG.

Table S1. Composition and molar amounts of precursors used for the preparation of perovskite solutions.

Perovskite Type	Precursor	Mass (mg)	Molar Mass (g/mol)	Amount (mmol)
<b>FA<sub>0.80</sub>MA<sub>0.12</sub>CS<sub>0.08</sub>Pb(I<sub>0.88</sub>Br<sub>0.12</sub>)<sub>3</sub></b>	PbI <sub>2</sub>	548.6	461.01	1.19
	PbBr <sub>2</sub>	57.06	367.01	0.155
	FAI	178.94	171.91	1.041
	MABr	17.41	111.97	0.155
	CsI	27.02	259.81	0.104
	Solvent (DMF:DMSO)			780 μL:220 μL
<b>FA<sub>0.92</sub>CS<sub>0.08</sub>Pb(I<sub>0.92</sub>Br<sub>0.08</sub>)<sub>3</sub></b>	PbI <sub>2</sub>	548.6	461.01	1.19
	PbBr <sub>2</sub>	57.06	367.01	0.155
	FAI	205.59	171.91	1.196
	CsI	27.02	259.81	0.104
		Solvent (DMF:DMSO)		

Table S2. Detailed composition of ammonium formate (AF) additive in perovskite precursor solutions with different concentrations.

Final Perovskite Composition	AF Amount (%mol)	Molar Mass of AF (g/mol)	Added AF (mg)	Sample Code
<b>FA<sub>0.92</sub>CS<sub>0.08</sub>Pb(I<sub>0.92</sub>Br<sub>0.08</sub>)<sub>3</sub></b>	0.00	63.06	0.00	AF0
	2.00	63.06	1.69	AF2
	4.00	63.06	3.38	AF4
	6.00	63.06	5.07	AF6